



Flash Memory Summit

# The Next Breakthrough in Non-Volatile Memory

**Jung H. Yoon**, IBM Supply Chain Engineering

Jim Handy, President, Objective Analysis

Rory Bolt, Sr. Fellow, Toshiba Memory Systems

Dr. Daniel Worledge, Sr Manager MRAM, IBM

Bill Gervasi, Principal Architect, Nantero

Leah Schoeb, Sr. Developer Relations System Architecture, AMD

# DRAM, NAND, SCM Cost Projections (by IBM)

